

<i>SEP 28 2004</i> <b>FIRST SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT</b> <small>TRADEMARK OFFICE</small>	ATTY. DOCKET NO. <b>2132.0180000</b>	APPLICATION NO. <b>10/796,413</b>
	FIRST NAMED INVENTOR <b>Xiangfeng Duan</b>	
	FILING DATE <b>March 10, 2004</b>	ART UNIT <b>2818</b>
	<b>U.S. PATENT DOCUMENTS</b>	

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE
AA1						
AB1						
AC1						
AD1						
AE1						
AF1						
AG1						
<i>M</i>	AH1	6,586,785	07/2003	Flagan et al.		
<i>M</i>	AI1	6,723,606	04/2004	Flagan et al.		
AJ1						
AK1						

**FOREIGN PATENT DOCUMENTS**

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION
						Yes
AL1						No
AM1						Yes
AN1						No
AO1						Yes
AP1						No

**OTHER (Including Author, Title, Date, Pertinent Pages, etc.)**

	AR	1	
<i>M</i>	AS	1	McCarthy, W., O'REILLY NETWORK™ Quantum Dots and Programmable Matter (visited January 12, 2004) <a href="http://www.oreillynet.com/pub/a/network/2004/01/09/quantumdots.html">http://www.oreillynet.com/pub/a/network/2004/01/09/quantumdots.html</a> , 5 pages, Copyright 2000-2004 O'Reilly & Associates, Inc.
<i>M</i>	AT	1	Mandal, S., "QUANTUM DOTS," E & ECE, IIT Kharagpur, Roll: 9819107, 24 pages, August 29, 2001.

EXAMINER

DATE CONSIDERED

*3/30/04*

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.

FORM PTO-1449 <b>INFORMATION DISCLOSURE STATEMENT</b>				ATTY. DOCKET NO. 2132.0180000	APPLICATION NO. To be assigned		
				FIRST NAMED INVENTOR Duan et al.			
				FILING DATE March 10, 2004	ART UNIT To be assigned		
<b>U.S. PATENT DOCUMENTS</b>							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE
<i>MN</i>	AA1	5,043,940	08/27/1991	Harari			07/17/1989
<i>MN</i>	AB1	5,434,825	07/18/1995	Harari			09/03/1993
<i>MN</i>	AC1	6,222,762 B1	04/24/2001	Guterman et al.			08/07/1997
<i>MN</i>	AD1	6,275,419 B1	08/14/2001	Guterman et al.			10/13/2000
<i>MN</i>	AE1	6,317,363 B1	11/13/2001	Guterman et al.			10/13/2000
<i>MN</i>	AF1	6,317,364 B1	11/13/2001	Guterman et al.			10/13/2000
<i>MN</i>	AG1	6,577,532 B1	06/10/2003	Chevallier			08/31/2000
	AH1						
	AI1						
	AJ1						
	AK1						
<b>FOREIGN PATENT DOCUMENTS</b>							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION
	AL1						Yes
	AM1						No
	AN1						Yes
	AO1						No
	AP1						Yes
							No
<b>OTHER (Including Author, Title, Date, Pertinent Pages, etc.)</b>							
<i>MN</i>	AR	1	Silicon Storage Technology, Inc., "Technical Comparison of Floating Gate Reprogrammable Nonvolatile Memories", Technical Paper, November 2001, copyright 2002, 8 pages.				
	AS	1					
	AT	1					
EXAMINER <i>MN EO</i>					DATE CONSIDERED <i>9/30/06</i>		
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							